

BF620 TRANSISTOR (NPN)

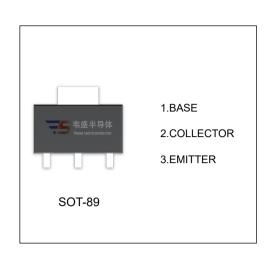
FEATURES

- Low current (max. 50mA)
- High voltage (max. 300V).
- Video output stages.

Marking: DC

MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit	
V _{CBO}	Collector-Base Voltage	ige 300		
V _{CEO}	Collector-Emitter Voltage	300	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current -Continuous	50	mA	
Pc	Collector Power Dissipation	500	mW	
T _J ,T _{stg}	Junction Temperature	-55~150	℃	



ELECTRICAL CHARACTERISTICS (Ta=25 $^{\circ}$ C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =100μA, I _E =0	300			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =1mA, I _B =0	300			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =100μA, I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} =200V, I _E =0			10	nA
Emitter cut-off current	I _{EBO}	V _{EB} =5V, I _C =0			50	nA
DC current gain	h _{FE}	V _{CE} =20V, I _C =25mA	50			
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =30mA, I _B =5mA			0.6	V
Transition frequency	f _T	V _{CE} =10V, I _C =10mA, f=100MHz	60			MHz